

MiniSKiiP[®] 3

Twelvepack

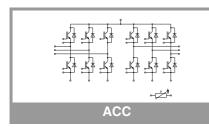
SKiiP 35ACC12F4V1

Features*

- Fast Trench 4 IGBTs
- Robust and soft freewheeling diodes in CAL technology
- Highly reliable spring contacts for electrical connections
- UL recognized: File no. E63532

Remarks

- Case temperature limited to $T_C=125^{\circ}C$ max.; $T_C = T_S$ (for baseplateless modules)
- Product reliability results valid for $T_j \le 150^{\circ}C$ (recommended $T_{iop} = -40... + 150^{\circ}C$)
- Inverter IGBT: IGBT 1 IGBT 12
- Inverse Diode: Diode 1 Diode 12
- The creepage distance between T-Sensor and DC- is 0,8mm (functional isolation of T-sensor only up to 200V)
- MiniSKiiP "Technical Explanations" and "Mounting Instructions" are part of the data sheet. Please refer to both documents for further information.



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Absolute	Maximum Rating	5				
Symbol	Conditions			Values		Unit
Inverter -	IGBT					
V _{CES}	T _j = 25 °C			1200		V
lc	λ_{paste} =0.8 W/(mK) T _j = 175 °C	T _s = 25 °C		54		
		T _s = 70 °C		43	Α	
I _C	λ_{paste} =2.5 W/(mK) T _j = 175 °C	T _s = 25 °C		62		Α
		T _s = 70 °C		50	Α	
I _{Cnom}				50		Α
I _{CRM}				150		Α
V _{GES}				-20 20		V
t _{psc}	$V_{CC} = 800 V$ $V_{GE} \le 15 V$ $V_{CES} \le 1200 V$	T _j = 150 °C		10		μs
T _i				-40 175		
Inverse -	Diode					1
V _{RRM}	T _i = 25 °C			1200		V
l _F	λ_{paste} =0.8 W/(mK) T _j = 175 °C	T _s = 25 °C		58	Α	
		T _s = 70 °C		46	Α	
l _F	λ _{paste} =2.5 W/(mK)	T _s = 25 °C		65	Α	
	T _j = 175 °C	T _s = 70 °C		52		Α
I _{FRM}	_			100		Α
I _{FSM}	t _p = 10 ms, sin 180°, T _j = 150 °C			270		
Tj				-40 175		
Module			•			
I _{t(RMS)}	T _{terminal} = 80 °C, 20 A per spring			40		
T _{stg}	module without TIM			-40 125		
V _{isol}	AC sinus 50 Hz, t = 1 min			2500		
Characte	eristics					
Symbol	Conditions		min.	typ.	max.	Unit
Inverter -	-					
V _{CE(sat)}	I _C = 50 A V _{GE} = 15 V chiplevel	T _j = 25 °C		2.05	2.42	V
		T _j = 150 °C		2.59	2.96	V
V _{CE0}		T _j = 25 °C		1.10	1.28	V
	- chiplevel	, T; = 150 °C		0.95	1 13	V

T_i = 150 °C

T_i = 25 °C

T_i = 150 °C

f = 1 MHz

f = 1 MHz

f = 1 MHz

T_i = 150 °C

T_i = 150 °C

T_i = 150 °C

T_i = 150 °C

0.95

19

33

5.8

2.77

0.21

0.16

283

4.0

28

21

4.8

234

47

3.4

0.87

0.69

5.2

1.13

23

37

6.4

1

mΩ

mΩ

V

mΑ

nF

nF

nF

nC

Ω

ns

ns

mJ

ns

ns

mJ

K/W

K/W

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V_{GE} = 15 V

 $V_{CE} = 25 V$

 $V_{GE} = 0 V$

 $T_i = 25 °C$

 $I_{\rm C} = 50 \, {\rm A}$

V_{CC} = 600 V

 $R_{G on} = 6.2 \Omega$

V_{GE} = +15/-15 V

 $R_{G off} = 0 \ \Omega$

 $V_{GE}=V_{CE},\,I_C=1.7\;mA$

V_{GE} = - 8 V...+ 15 V

V_{GE} = 0 V, V_{CE} = 1200 V, T_i = 25 °C

di/dt_{on} = 2508 A/µs | T_j = 150 °C

 $di/dt_{off} = 1082 \text{ A/}\mu \text{s}$ $T_i = 150 \text{ °C}$

per IGBT, λ_{paste}=0.8 W/(mK)

per IGBT, λ_{paste}=2.5 W/(mK)

chiplevel

 r_{CE}

V_{GE(th)}

ICES

Cies

Coes

C_{res}

 Q_{G}

R_{Gint}

t_{d(on)}

tr

 E_{on}

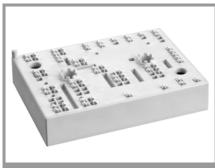
t_{d(off)}

t_f

Eoff

R_{th(j-s)}

R_{th(j-s)}



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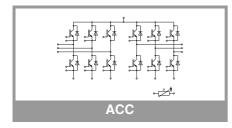
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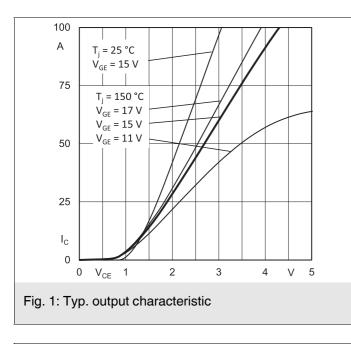
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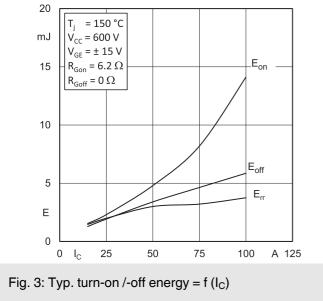
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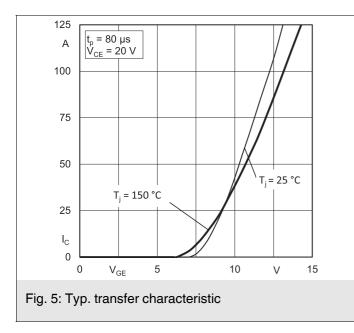
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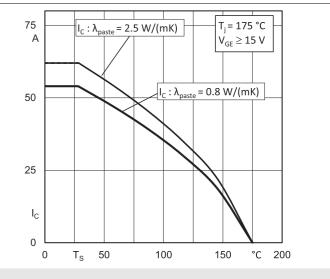
Characte	eristics					
Symbol	Conditions	min.	typ.	max.	Unit	
Inverse -						
$V_F = V_{EC}$	$I_{\rm F} = 50 {\rm A}$	T _j = 25 °C		2.22	2.54	V
	V _{GE} = 0 V chiplevel	T _j = 150 °C		2.18	2.50	V
V _{F0}	chiplevel	T _j = 25 °C		1.30	1.50	V
		T _j = 150 °C		0.90	1.10	V
r _F	chiplevel	T _j = 25 °C		18	21	mΩ
		T _j = 150 °C		26	28	mΩ
I _{RRM}	di/dt _{off} = 2426 A/µs V _{GE} = +15/-15 V	T _j = 150 °C		90.1		Α
Q _{rr}		T _j = 150 °C		8.25		μC
E _{rr}		T _j = 150 °C		3		mJ
R _{th(j-s)}	per Diode, λ_{paste} =0.8 W/(mK)			1.02		K/W
R _{th(j-s)}	per Diode, λ_{paste} =2.5 W/(mK)			0.84		K/W
Module						
L _{CE}				-		nH
Ms	to heat sink		2		2.5	Nm
w				82		g
Temperat	ure Sensor					
R ₁₀₀	T _r =100°C (R ₂₅ =1000Ω)			1670 ± 3%		Ω
R _(T)	$ \begin{array}{l} R_{(T)} = 1000\Omega[1 + A(T\text{-}25^\circ\text{C}) + B(T\text{-}25^\circ\text{C})^2] \\ \text{, } A = 7.635^*10^{-3\circ}\text{C}^{-1}, \\ B = 1.731^*10^{-5\circ}\text{C}^{-2} \end{array} $					

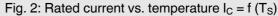


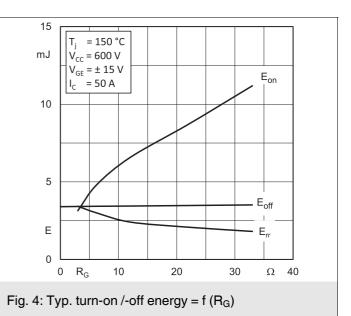


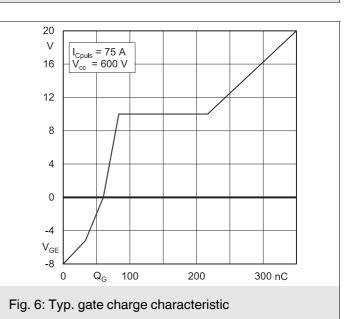




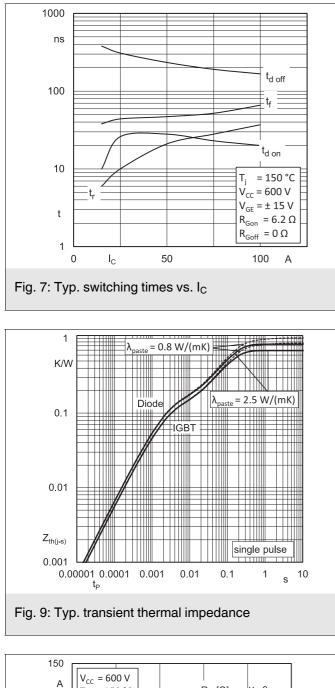


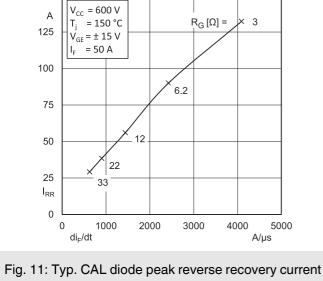


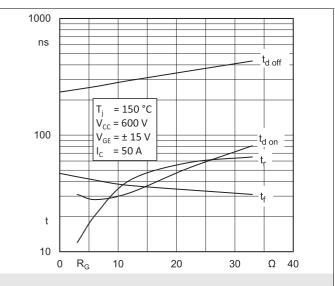


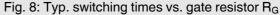


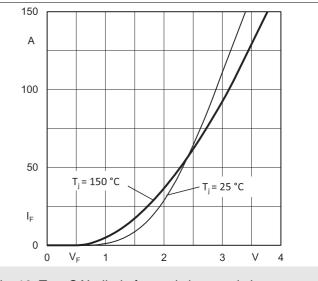


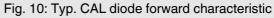


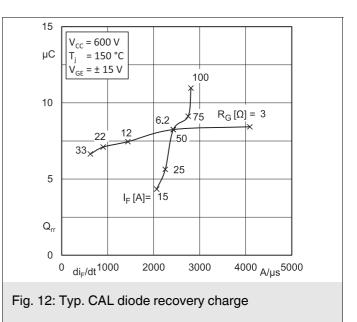


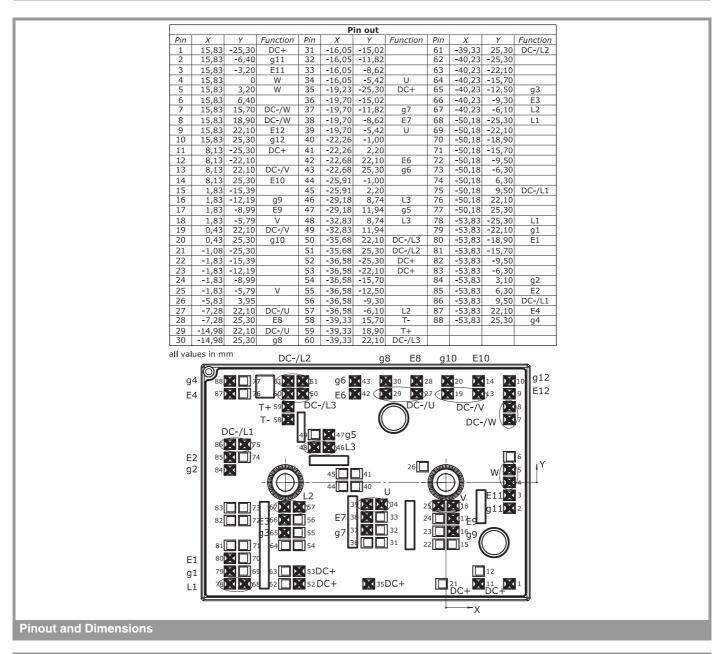


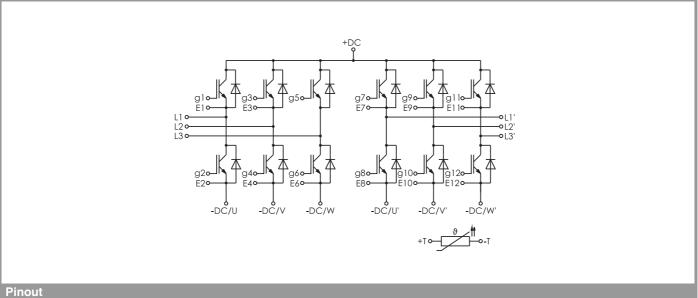












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This is an electrostatic discharge sensitive device (ESDS) due to international standard IEC 61340.

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